Quartic Lattice Interactions, Soliton-Like Excitations, and Electron Pairing in One-Dimensional Anharmonic Crystals

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In this study, it is shown that two added, excess electrons with opposite spins in one-dimensional crystal lattices with quartic anharmonicity may form a bisolectron, which is a localized bound state of the paired electrons to a soliton-like lattice deformation. It is also shown that when the Coulomb repulsion is included, the wave function of the bisolectron has two maxima, and such a state is stable in lattices with strong enough electron (phonon/soliton)–lattice coupling. Furthermore, the energy of the bisolectron is shown to be lower than the energy of the state with two separate, independent electrons, as even with account of the Coulomb repulsion the biso electron binding energy is positive. © 2011 Wiley Periodicals, Inc.

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Introduction

In a previous publication,[1] we have considered soliton-mediated electron pairing in anharmonic lattices endowed with cubic interparticle interaction. The latter is of mathematical interest, as it underlies as a dynamical system the soliton-bearing Boussinesq–Korteweg-de Vries equation governing wave propagation along the lattice in the continuum approximation.[2–4] Noteworthy is that due to the electron–lattice interaction, the soliton arising from the cubic interaction is able to trap an electron, thus, leading to a solectron[5–7] in a way that generalizes the polaron concept long ago proposed by Landau and Pekar to describe electron self-trapping leading to a dressed electron (or, more generally, a quasiparticle).[8–11] In Ref. [1], it was shown that when two excess electrons are added the corresponding electron–lattice interaction also facilitates electron pairing leading to a biso electron, that is, the localized bound state of the paired electrons and a soliton-like lattice deformation (otherwise said strongly correlated electrons in real space and momentum space). Here, we study this problem for a lattice with the apparently more physically appealing quartic particle interaction.

Hamiltonian and Evolution Equations

We consider a one-dimensional (1D) model, infinitely long crystal lattice with electrons and lattice particles of equal masses \( M \), describable by the following Hamiltonian:[10,11]

\[
\hat{H} = \hat{H}_{\text{el}} + \hat{H}_{\text{lat}} + \hat{H}_{\text{int}},
\]

with

\[
\hat{H}_{\text{el}} = \sum_{n,s} \left[ E \hat{b}_{n,s}^\dagger \hat{b}_{n,s} - \frac{\hbar^2}{2M} \left( \hat{\mathbf{p}}_{n,s}^2 + \hat{\mathbf{U}} \right) \right],
\]

\[
\hat{H}_{\text{lat}} = \frac{\hbar^2}{2M} \sum_n \left( \hat{\mathbf{p}}_{n,1}^2 - \hat{\mathbf{U}} \right),
\]

\[
\hat{H}_{\text{int}} = \chi \sum_{n,s} \left( \hat{\beta}_{n+1,s} \hat{\beta}_{n+1,s}^\dagger \hat{\beta}_{n,s} \hat{\beta}_{n,s}^\dagger \right).
\]
Note that we have two added excess electrons with opposite spins, \( s = \uparrow, \downarrow \). The quantity \( E_0 \) denotes the on-site electron energy, \( J \) denotes the electron exchange interaction energy, \( \hat{B}^\dagger_n \) and \( \hat{B}_n \) are creation and annihilation operators of an electron with spin \( s \) on the lattice site \( n \), respectively, \( \hat{\rho}_n \) is the displacement operator of the \( n \)th atom from its equilibrium position, \( \hat{\rho}_n \) is the operator of the canonically conjugated momentum, \( z \) accounts for the electron–lattice interaction strength, and \( \hat{U} = \hat{U}(\{\hat{\rho}_n\}) \) is the operator of the potential energy of the lattice, yet to be specified. Only nearest neighbor interactions will be considered, and therefore, the lattice potential energy depends on their relative displacements:

\[
U(\{\hat{\rho}_n\}) = U(\hat{\rho}_n - \hat{\rho}_{n+1}) \equiv U(\rho_n),
\]

where \( \rho_n \equiv \hat{\rho}_n - \hat{\rho}_{n+1} \). We take into account only the longitudinal displacements of atoms from their initial equilibrium positions (the acoustic mode) and consider that the dependence of the on-site electron energy on lattice atom displacements is much stronger than that of the exchange interaction energy. Further, the electron–lattice interaction is taken strong enough so that the electron self-trapping leads to a bound state whose length extends over several lattice sites. The Coulomb repulsion between the electrons will be included later on.

For two electrons with opposite spins, the antisymmetry of the two-electron spin function permits representing the two-electron spatial wave-function as a symmetrized product of one-electron wave-functions, \( \psi_{j,n} \), \( j = 1, 2 \). The evolution equations for \( \psi_{j,n} \) and for the lattice deformation, \( \rho_n \), follow from the variational minimization condition of the Hamiltonian functional obtained from Hamiltonian Eq. (1). This functional depends on the canonical variables \( \psi_{j,n} \) and \( \rho_n \) and their canonically conjugate momenta. In the continuum approximation, defining \( z = na \), with \( a \) being the initial equilibrium lattice interparticle spacing we have:

\[
\begin{align*}
\hbar \frac{\partial \psi_j(z, t)}{\partial t} + J \hbar \frac{\partial^2 \psi_j(z, t)}{\partial z^2} = -\gamma a \frac{\partial \psi_j(z, t)}{\partial z} \psi_j(z, t) = 0, \\
\frac{\partial^2 \rho(z, t)}{\partial t^2} - V_{\text{sc}} \frac{\partial^2 U(z, t)}{\partial \rho^2} = \frac{\gamma a}{M} \frac{\partial \rho(z, t)}{\partial z} \left( |\psi_1(z, t)|^2 + |\psi_2(z, t)|^2 \right),
\end{align*}
\]

where

\[
\rho(z, t) = -\frac{\partial \psi(z, t)}{\partial z},
\]

here, \( V_{\text{sc}} = \alpha^2 w/M \) is the sound velocity in the lattice with \( w \) being the lattice elasticity constant.

For the lattice interparticle interaction, \( U(\rho) \), we take:

\[
U(\rho) = \frac{1}{2} \rho^2 + \frac{\gamma}{4} \rho^4.
\]

Here, we are only interested in the effect of the quartic curvature of the potential relative to the harmonic case and not on the possible influence of a double-well potential.

The one-electron wave functions in the system of coupled nonlinear Eqs. (6) and (7) satisfy the normalization condition

\[
\frac{1}{a} \int_{-\infty}^{\infty} |\psi_j(z, t)|^2 dz = 1 \quad (j = 1, 2),
\]

and for the stationary states can be written in the form:

\[
\psi_j(z, t) = \Phi_j(\xi) \exp\left\{ \frac{1}{\hbar} \left[ mvz - E_j t - \frac{1}{2} mVz^2 \right] + i\phi_j(t) \right\} \quad (j = 1, 2),
\]

where \( \Phi_j(\xi) \) is a one-electron envelope function in terms of the running wave variable \( \xi = (z - z_0 - Vt)/a \). Here, \( E_j \) is the eigen-energy, \( \phi_j(t) \) is the phase, and \( m = \hbar^2/(2Ja^2) \) is the effective mass of an electron. Note that in the absence of extra electrons in the lattice the wave velocity depends on the actual lattice compression, \( \rho \), determined by Eq. (8), and may increase or decrease with amplitude, though for the Toda, Morse, and Lennard–Jones potentials it is an always increasing function of the wave amplitude. Note also that for steady motions \( V \) is constant.

In 1D systems, the deformational potential has at least one bound state, and the minimum of the energy of the system corresponds to the state where the two electrons occupy the same level in the common potential well. In the general case, the maximum values of the electron wave functions are shifted along the lattice at some value, \( la \), which is determined by the balance between the expected Coulomb repulsion between the electrons and their lattice-mediated attraction, similar to the case of binding of two extra electrons in a harmonic lattice. Therefore, we can write

\[
\Phi_j(\xi) = \Phi(\xi \pm l/2)f_j(l),
\]

where, we have considered that the functions \( f_j(l) \) take into account the modulation of one-electron wave functions due to the Coulomb repulsion. If for localized states extending over several lattice sites the repulsion is weak enough, then \( f_j(l) \approx 1 + \varepsilon \phi_j(l) \), where \( \varepsilon \) is a smallness parameter, \( \varepsilon \ll 1 \). In the lowest order, approximation with respect to \( \varepsilon \) the maxima of both one-electron functions coincide at \( \xi = 0 \) (this is always possible by the appropriate choice of \( z_0 \)), and, correspondingly, the two eigen-energies and eigen-functions are equal:

\[
E_1 = E_2 \equiv E \quad \Phi_1(\xi) = \Phi_2(\xi) \equiv \Phi(\xi).
\]

For universality in the argument, let us introduce the following dimensionless parameters:

\[
\lambda = -\frac{E}{J}, \quad \sigma = \frac{\gamma a}{J}, \quad D = \frac{\gamma a}{MV^2_{\text{sc}}},
\]

From Eqs. (6) and (8) using Eq. (9) follows:

\[
\frac{d^2\Phi(\xi)}{d\xi^2} + \sigma \rho(\xi)\Phi(\xi) = \lambda \Phi(\xi).
\]
\[ \Phi^2(\xi) = \frac{1}{2D} \frac{dF(\rho)}{d\rho}, \] (16)

where

\[ F(\rho) = U(\rho) - \frac{1}{2} \sigma^2 \rho^2 - \frac{1}{4} \gamma \rho^2 + 2\delta. \] (17)

Here, \( \sigma^2 = \nu^2 / \nu_\infty^2 \), and

\[ \delta = 1 - \frac{s^2}{\gamma}. \] (18)

is the dynamically modulated inverse anharmonic stiffness coefficient.

### Localized Solutions

From Eq. (15) we get

\[ \left( \frac{d\Phi}{d\xi} \right)^2 = \lambda \Phi^2(\xi) - \sigma Q(\xi) \] (19)

with

\[ Q(\xi) = \int_{-\infty}^{\xi} \rho(x) d\Phi^2(x). \] (20)

We search for localized solutions of Eqs. (15) and (16) which exponentially decay in space and attain some maximum values, which we denote by \( \Phi_0 \) and \( \rho_0 \), for the wave-function and corresponding deformation, respectively. From Eq. (19) we get the electron eigen-energy:

\[ \lambda = \sigma \frac{Q(0)}{\Phi_0^2}. \] (21)

From Eq. (16) we get

\[ d\Phi^2(\xi) = \frac{1}{2D} d \left( \frac{dF}{d\rho} \right). \] (22)

that substituted into Eq. (19) yields, after integration, the following equation:

\[ F(\rho) = \frac{1}{2D} \int_{0}^{\rho} \rho' \left( \frac{dF}{d\rho'} \right) = \frac{1}{2D} \frac{dF}{d\rho} G(\rho), \] (23)

where

\[ G(\rho) = \rho - \frac{F(\rho)}{dF/d\rho} = \rho \frac{3\sigma^2 + 2\delta}{4 \rho^2 + \delta}. \] (24)

Differentiating Eq. (15) with respect to \( \xi \), we get

\[ \left( \frac{d\Phi}{d\xi} \right)^2 = \frac{1}{2D} \left( \frac{dF}{d\rho} \right)^2 + \left( \frac{d\rho}{d\xi} \right)^2. \] (25)

Then, from Eq. (19) we have

\[ \left( \frac{d\Phi(\xi)}{d\xi} \right)^2 = \frac{1}{2D} \frac{dF}{d\rho} (\lambda - \sigma G). \] (26)

Equations (25) and (26) yield the equation for the lattice deformation:

\[ \frac{d\rho}{d\xi} = \pm 2 \sqrt{\sigma} \frac{dF/d\rho}{dF/d\rho^2} \sqrt{G(\rho_0) - G(\rho)}, \] (27)

where we have taken into account the relation

\[ \lambda = \sigma G(\rho_0), \] (28)

which follows from Eq. (21). Indeed to obtain Eq. (27), we first get \( \frac{d\rho}{d\xi} \) from Eq. (25), take into account Eqs. (20) and (22), and then integrate the result by parts:

\[ Q(0) = \int_{-\infty}^{0} \rho(x) d\Phi^2(x) = \int_{-\infty}^{0} \rho(x) \frac{1}{2D} d \left( \frac{dF}{d\rho} \right) = \frac{1}{2D} \left[ \frac{dF}{d\rho} \left( \rho - \frac{F}{dF/d\rho} \right) \right]_{\rho \to \rho_0} = \Phi_0^2 G(\rho_0). \] (29)

Then, integrating Eq. (3.9), we get

\[ \xi(\rho) = \pm \frac{1}{2 \sqrt{\sigma}} \int_{\rho_0}^{\rho} d\rho' \frac{dF/d\rho'^2}{\sqrt{G(\rho_0) - G(\rho)}}. \] (30)

The difference function in the kernel of Eq. (30) can be rewritten as

\[ G(\rho_0) - G(\rho) = (\rho_0 - \rho) \Theta(\rho, \rho_0), \] (31)

with

\[ \Theta(\rho, \rho_0) = \frac{3\sigma^2 \rho^2 + \delta (3\sigma^2 \rho_0 + \rho \delta) - 2\delta^2}{4(\rho^2 + \delta)(\rho_0^2 + \delta)}. \] (32)

Taking into account Eq. (31), Eq. (30) becomes

\[ \xi(\rho) = \pm \frac{1}{2 \sqrt{\sigma}} \int_{\rho_0}^{\rho} \frac{\hat{K}(\rho, \rho_0)}{\sqrt{\rho_0 - \rho}} d\rho, \] (33)

where

\[ K(\rho, \rho_0) = \frac{1}{\sqrt{2 \Theta(\rho, \rho_0)}} \frac{3\sigma^2 \rho^2 + \delta}{\rho^2 + \delta}. \] (34)

Then in view of Eq. (32), the expression Eq. (34) shows a weak dependence of \( K \) on its variables. Practically, it remains in value very close to a constant equal to unity. The quantity \( K(\rho, \rho_0) \) Eq. (34) is plotted in Figure 1 for \( \delta = 0.5 \). Note that \( K \) varies 4% only, from 1 to 1.04. Only the part of the plot for \( \rho < \rho_0 \) has physical meaning as by definition \( \rho_0 \) defines the maximum value of \( \rho \).
Taking this into account, we can integrate Eq. (30), which gives

\[ q(n) = q_0 \text{Sech}^2(jn), \]  

(35)

with

\[ j = \sqrt{\frac{\sigma q_0}{2}}, \]  

(36)

defining the inverse width spanned by the lattice deformation. The maximum value of the lattice deformation can be found from the normalization condition Eq. (10), which takes the form

\[ 1 = \int_0^{\rho_0} \frac{dF}{dp} |d(z(p))| dp, \]  

(37)

from which we get

\[ \int_0^{\rho_0} \frac{d^2F}{dp^2} \sqrt{G(p_0) - G(p)} dp = 2D\sqrt{\sigma}. \]  

(38)

Substituting the relation Eq. (32) into Eq. (38) and using Eq. (17), we get

\[ \int_0^{\rho_0} \frac{3\rho^2 + \delta}{\sqrt{(\rho_0 - \rho)}(p_0)} dp = \frac{2D}{\gamma} \sqrt{\sigma}. \]  

(39)

Function \( \Theta(p, \rho_0) \) shows quite a weak dependence on \( \rho \) and can be approximated by its value at \( \rho = \rho_0 \):

\[ \Theta(p, \rho_0) \approx \Theta(\rho_0, \rho_0) \equiv \delta(\rho_0) = \frac{3\rho_0^4 + 7\delta\rho_0^2 + 2\delta^2}{\rho_0^4 + 2\delta\rho_0^2 + \delta^2}. \]  

(40)

Figures 2a and 2b illustrate the behavior of Eq. (32) and Eq. (40), respectively.

Using Eq. (40), we get from Eq. (39) the equation for the maximum value of deformation

\[ \rho_0 \left( \frac{8}{5} \rho_0^2 + \delta \right) = \frac{\lambda^2}{4} \delta(\rho_0). \]  

(41)

where \( \lambda \) is the dimensionless electron–lattice coupling constant:

\[ \lambda^2 = \frac{4D^2}{p^2}. \]  

(42)

The maximum value of the lattice deformation in Eq. (41) as function of the dynamically modulated inverse anharmonic stiffness coefficient \( \delta \), is depicted in Figure 3 for two values of the electron–lattice coupling constant, \( \lambda = 0.05 \) and \( \lambda = 0.2 \). It appears that the faster is the bisolectron, the higher amplitude it has, determined by \( \rho_0 \) and the narrower its width is, \( \Lambda = 2\alpha \lambda / \kappa \). Nevertheless, it does not shrink completely, its amplitude and width maintain finite values even when the bisolectron approaches the sound velocity, \( V = V_{ac}(s = 1, \delta = 0) \). This result is at variance to the case of the harmonic approximation in the lattice potential Eq. (8).\(^{12,13}\) For
comparison, we also show the results of cubic anharmonicity (thin line) for the same values of $\alpha$ in Figure 3. It appears that the stronger is the electron–lattice coupling constant, the bigger is the maximum value of the deformation. The quartic anharmonicity is dominant at small values of $\delta$ Eq. (18), which is the velocity rescaled inverse anharmonic stiffness coefficient.

Substituting the result Eq. (36) into Eq. (16) and using Eq. (17), we obtain the electron wave-function:

$$\Phi(\xi) = \sqrt{\frac{\rho_0}{2D}} \text{Sech}(\kappa \xi) \sqrt{1 - s^2 + \gamma \rho_0^2 \text{Sech}^4(\kappa \xi)},$$  \hspace{1cm} (43)

and the corresponding maximum of the wave function:

$$\Phi_0 = \sqrt{\frac{1}{2D}} \left( \frac{dF}{dp} \right)_{p = p_0} = \sqrt{\frac{\gamma}{2D}} \rho_0 (\rho_0^2 + \delta).$$  \hspace{1cm} (44)

### Energy of the Bisolectron and Role of the Coulomb Repulsion

Let us calculate the energy and momentum of the system. For Eq. (1) with the solutions Eq. (35), Eq. (43) (without Coulomb repulsion) we get

$$E^{(\text{bi})}(V) = mV^2 + E^{(\text{bi})}(V) + W(V),$$  \hspace{1cm} (45)

where the bisolectron energy and energy of the lattice deformation are, respectively, given by the expressions:

$$E^{(\text{bi})}(V) = -2ij = -2DG(\rho_0)MV_{\text{ac}}^2,$$  \hspace{1cm} (46)

$$W(V) = 2MV_{\text{ac}}^2 \int_0^\infty (F(p) + s^2 \rho^2) d\rho,$$

$$= \frac{MV_{\text{ac}}^2}{\sqrt{\sigma}} \int_0^{\rho_0} \frac{dF/d\rho}{\sqrt{G(\rho_0) - G(\rho)}} d\rho.$$  \hspace{1cm} (47)

The total momentum of the system is

$$P(V) = \left( 2m + M \int_{-\infty}^\infty \rho^2 d\xi \right) V = \left( 2m + M \int_0^{\rho_0} \frac{d^2F/d\rho^2}{\sqrt{G(\rho_0) - G(\rho)}} d\rho \right) V.$$  \hspace{1cm} (48)

Substituting here the explicit expressions of $F$ given by Eq. (17) and its derivatives, we get the bisolectron energy, energy of the deformation, and momentum of the system, respectively:

$$E^{(\text{bi})}(V) = \frac{1}{2} \frac{DMV_{\text{ac}}^2 \rho_0^3}{\rho_0^2 + \delta} 3 \rho_0^2 + 2 \delta \rho_0^2.$$  \hspace{1cm} (49)

$$W(V) \approx \frac{MV_{\text{ac}}^2}{2\sqrt{2\sigma}} \int_0^{\rho_0} K(\rho, \rho_0) \rho \gamma p^2 + 4(s^2 + \frac{1}{2} \gamma) d\rho$$

$$\approx 8 \frac{MV_{\text{ac}}^2}{\sqrt{2\sigma}} \frac{3\rho_0^2}{\rho_0^3} \left[ \frac{1}{3} \left( s^2 + \frac{1}{2} \gamma \rho_0^2 \right) + \frac{2}{35} \gamma \rho_0^2 \right].$$  \hspace{1cm} (50)

$$P(V) = \left( 2m + M \int_0^{\rho_0} \frac{d^2F/d\rho^2}{\sqrt{G(\rho_0) - G(\rho)}} d\rho \right) V \approx \left[ 2m + \frac{4}{3} M \rho_0^{3/2} \right] V.$$  \hspace{1cm} (51)

According to Eq. (11), the bisolectron moves along the lattice with constant velocity $V \leq V_{\text{ac}}$ and momentum

$$P = M^{(\text{bi})}_\text{eff} V,$$  \hspace{1cm} (52)

where $M^{(\text{bi})}_\text{eff}$ is its effective mass, which, as it follows from the expression Eq. (4.7), is given by the relation

$$M^{(\text{bi})}_\text{eff} \approx 2m + \frac{4}{3} M \sqrt{\frac{2J}{\rho_0^6}} \rho_0^{3/2}.$$  \hspace{1cm} (53)

It depends on both the velocity and lattice anharmonicity parameter through the corresponding dependence of the value of the maximum deformation, and, therefore, it attains the maximum value at $V = V_{\text{ac}}$. It is the essential feature of the anharmonic lattice that at the maximum value of the
two peaks in the bisolectron wave-function equal to two and three lattice sites, respectively. Note that the lattice deformation is proportional to \( q(\xi) \), as it follows from Eq. (8) for the stationary case \( V = 0 \). This is reminiscent of what is detected with the scanning tunneling microscopy (STM). In related publications,\(^{5,14-16}\) we have made use of this methodology for tracking soliton excitations both in 1D and 2D lattices.

As the bisolectron spans few lattice sites, we can use the approximation

\[
E_c \approx \frac{e^2}{4\varepsilon_0a}.
\]

where \( e \) is the electron charge and \( \varepsilon_0 \) is the dielectric constant. Then, to elucidate the role of the Coulomb repulsion, we can approximate Eq. (54) by

\[
\Phi_\xi(\xi) \approx \sqrt[3]{\frac{\rho_0}{2D}} \text{Sech} \left[ \kappa \left( \xi \pm \frac{1}{2} \right) \right].
\]

Comparison of plots of functions Eqs. (54) and (56) and their corresponding charge distributions shows that for physically relevant parameter values (not too high values of \( \kappa \) to allow the wave functions spanning several lattice sites) the difference is negligibly small.

Substituting now Eq. (56) into the Hamiltonian Eq. (1) and expanding the wave functions and corresponding lattice deformation with respect to \( l \), we obtain after integration the total energy of the system including the Coulomb repulsion Eq. (55):

\[
E^{(bs)} = 2E_0 + \frac{2}{3} J \kappa^2 \rho_0 \frac{\gamma}{D} - \frac{4\gamma\alpha_0^2}{\kappa D} (1 - \hat{F} \kappa^2)
+ \omega a^2 \rho_0^2 \left( \frac{1}{3} + \frac{1}{3} \gamma \rho_0^2 \right) + \frac{e^2}{4\varepsilon_0a}. \tag{57}
\]

Minimizing this expression with respect to the distance between the maxima of one-electron functions, \( l \), we get the equilibrium distance

\[
l_0 \approx \frac{1}{2} \left( \frac{e^2}{\pi \varepsilon_0 a^2} \right)^{1/3}. \tag{58}
\]

with

\[
\zeta = \left[ \frac{4\gamma\alpha_0^2 \kappa}{3D} - \omega a^2 \rho_0^2 \left( \frac{1}{3} + \frac{1}{3} \gamma \rho_0^2 \right) \right]^{1/3}.
\]

As \( \rho_0 \ll 1 \), the equilibrium distance between the wave function peaks can be approximated as

\[
l_0 \approx \frac{1}{2} \left( \frac{3De^2}{4\varepsilon_0\pi a^2} \right)^{1/3}. \tag{60}
\]

Then with the Coulomb repulsion between the electrons, \( E_c \), the binding energy of the bisolectron is

\[
E_{\text{bind}} = 2E^{(s)} - E^{(bs)} - E_c. \tag{61}
\]
where $E^{(s)}$ is the energy of the system with a single added, excess electron as obtained in Refs. [11,17]. Comparing $E^{(s)}$ for $l = l_0$ with $E^{(s)}$ it results that $E_{\text{ind}} > 0$. Thus, in spite of the stronger Coulomb repulsion in the bisoelectron state, with spacing $l_0$ between the wave-function maxima, there is gain of energy due to pairing relative to the case of two separate electrons, placed at very large distance from each other.

Conclusions

It has been shown that the quartic anharmonicity in lattice interactions facilitates binding of two electrons in a singlet spin bisoelectron state, spanning a few lattice sites. Such a bisoelectron can move along the lattice with finite effective mass Eq. (53) and constant velocity. Moreover, the lattice anharmonicity limits bisoelectron energy and momentum up to the sound velocity in the lattice whereas biseolttons in harmonic lattices are unstable at velocities higher than some critical value, $V > V_{cl}$, below the sound velocity, $V_{cl} < V_{sq}$.[13]

Because of the Coulomb repulsion between the electrons the two-electron wave function may have a one-hump envelope at not too strong repulsion or a two-hump envelope at high enough repulsion strengths. In the latter case, the distance between the humps is determined by the balance between the gain of energy due to the coupling of electrons with the lattice and the lowering of energy due to the Coulomb repulsion. In systems with moderate electron–lattice interaction, the bisoelectron wave function is spread over few lattice sites and the distance between the two peaks of the bisoelectron wave function is 2–3 lattice sites or more. In such a state the energy of the bisoelectron is lower than the energy of the state with two separate, independent soelectrons, and even with account of the Coulomb repulsion the bisoelectron wave function Eq. (59) is positive. Thus, the bisoelectron state Eq. (43) is indeed a bound state of two added, excess electrons with antiparallel spins in the common potential well determined by the soliton-like lattice deformation Eq. (35). The results here reported complement and confirm earlier fragmented results obtained by computer simulations using the Gaussian approximation to the soliton excitation[18] and the harmonic and Morse potentials.[19–21] For interesting related work see the recent papers by Lyra and collaborators.[22,23]

In view of the above, it appears worth exploring the relationship of our bisoelectron with Alexandrov’s bipolaron.[24] His prediction was a finite small bipolaron bandwidth and a high critical superconducting temperature in the crossover region from the Bardeen-Cooper-Schrieffer (BCS) to bipolaronic superconductivity. What the bisoelectron and a multipolaron and multioletron dynamics share in common supporting the mentioned prediction?

Finally, let us give some examples of systems, in which bisoelectrons can exist. The crucial reason for their existence is the validity of the adiabatic approximation used in deriving the equations of motion in the form Eqs. (6) and (7). According to Refs. [25,26], this approximation is valid for quasi-1D systems, whose dimensionless electron–phonon coupling constant $g = \frac{\eta^2}{2\hbar\omega}$ and nonadiabaticity parameter $\gamma_{\text{non-ad}} = \hbar\nu_c / 2\Delta$ take value within certain intervals, which distinguish the regime of spontaneous electron localization as the crossover between the regimes of the formation of small polaron and almost free electron, respectively. To systems with such values of the electron–phonon coupling constant and nonadiabaticity parameter belong polydiacetylene,[27–29] conducting platinum chain compounds such as RbCP(FHF), RbCP(DSH), CsCP(FHF), CsCP(Cl), KCP(Cl), CsCP(N3), KCP(Br), PbCP(Cl), GCP(Cl), ACP(Cl).[30] There is also experimental evidence of the formation of large polarons in high-temperature superconducting cuprates[31–36] and salts of transition metals, such as PbSe, PbTe, and PbS,[37–40] at not too high values of the corresponding doping. Hence, we expect formation of bisoelectrons in all the above cited materials. We plan to explore this issue in future studies. The relation between the superconducting transition and the doping level in high-Tc superconductors points to the close relation of this phenomenon with the electron–phonon (soliton) coupling strength.

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